

Dual N-Channel 20-V MOSFET

| PRODUCT SUMMARY | | | |
|---------------------|----------------------------------|------------------------------------|-----------------------|
| V _{DS} (V) | R _{DS(on)} (Ω) | I _D (A) ^{a, g} | Q _g (Typ.) |
| 20 | 0.216 at V _{GS} = 4.5 V | 1.5 | 1.2 nC |
| | 0.268 at V _{GS} = 2.5 V | 1.5 | |
| | 0.375 at V _{GS} = 1.8 V | 1.0 | |

FEATURES

- Halogen-free
- TrenchFET[®] Power MOSFET
- New Thermally Enhanced PowerPAK[®] SC-75 Package
 - Small Footprint Area
 - Low On-Resistance

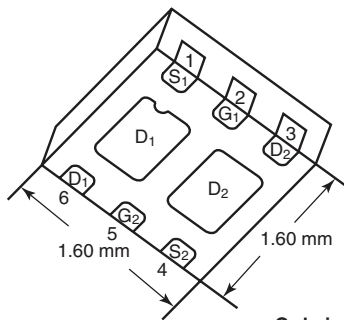


RoHS
COMPLIANT

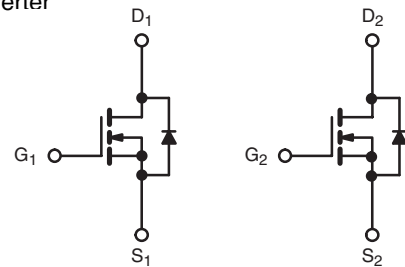
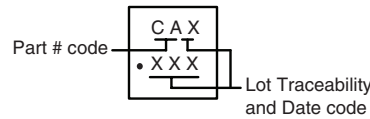
APPLICATIONS

- Load Switch, PA Switch and Battery Switch for Portable Devices
- DC/DC Converter

PowerPAK SC75-6L-Dual



Marking Code



Ordering Information: SiB912DK-T1-GE3 (Lead (Pb)-free and Halogen-free) N-Channel MOSFET N-Channel MOSFET

| ABSOLUTE MAXIMUM RATINGS T _A = 25 °C, unless otherwise noted | | | | |
|---|-----------------------------------|------------------------|------------------------|---|
| Parameter | Symbol | Limit | Unit | |
| Drain-Source Voltage | V _{DS} | 20 | V | |
| Gate-Source Voltage | V _{GS} | ± 8 | | |
| Continuous Drain Current (T _J = 150 °C) | I _D | T _C = 25 °C | 1.5 ^a | A |
| | | T _C = 70 °C | 1.5 ^a | |
| | | T _A = 25 °C | 1.5 ^{a, b, c} | |
| | | T _A = 70 °C | 1.4 ^{b, c} | |
| Pulsed Drain Current | I _{DM} | 5 | | |
| Continuous Source-Drain Diode Current | I _S | T _C = 25 °C | 1.5 ^a | |
| | | T _A = 25 °C | 0.9 ^{b, c} | |
| Maximum Power Dissipation | P _D | T _C = 25 °C | 3.1 | W |
| | | T _C = 70 °C | 2.0 | |
| | | T _A = 25 °C | 1.1 ^{b, c} | |
| | | T _A = 70 °C | 0.7 ^{b, c} | |
| Operating Junction and Storage Temperature Range | T _J , T _{stg} | - 55 to 150 | °C | |
| Soldering Recommendations (Peak Temperature) ^{d, e} | | 260 | | |

| THERMAL RESISTANCE RATINGS | | | | | |
|---|-------------------|---------|---------|------|--|
| Parameter | Symbol | Typical | Maximum | Unit | |
| Maximum Junction-to-Ambient ^{b, f} | R _{thJA} | 90 | 115 | °C/W | |
| Maximum Junction-to-Case (Drain) | R _{thJC} | 32 | 40 | | |

Notes:

- Package limited.
- Surface Mounted on 1" x 1" FR4 board.
- t = 5 s.
- See Solder Profile (<http://www.vishay.com/ppg?73257>). The PowerPAK SC-75 is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.
- Rework Conditions: manual soldering with a soldering iron is not recommended for leadless components.
- Maximum under Steady State conditions is 125 °C/W.
- Based on T_C = 25 °C.



| SPECIFICATIONS $T_J = 25\text{ }^\circ\text{C}$, unless otherwise noted | | | | | | |
|--|-------------------------|---|------|-------|------------------|---------------|
| Parameter | Symbol | Test Conditions | Min. | Typ. | Max. | Unit |
| Static | | | | | | |
| Drain-Source Breakdown Voltage | V_{DS} | $V_{GS} = 0\text{ V}$, $I_D = 250\text{ }\mu\text{A}$ | 20 | | | V |
| V_{DS} Temperature Coefficient | $\Delta V_{DS}/T_J$ | $I_D = 250\text{ }\mu\text{A}$ | | 22 | | mV/°C |
| $V_{GS(th)}$ Temperature Coefficient | $\Delta V_{GS(th)}/T_J$ | | | - 2 | | |
| Gate-Source Threshold Voltage | $V_{GS(th)}$ | $V_{DS} = V_{GS}$, $I_D = 250\text{ }\mu\text{A}$ | 0.4 | | 1.0 | V |
| Gate-Source Leakage | I_{GSS} | $V_{DS} = 0\text{ V}$, $V_{GS} = \pm 8\text{ V}$ | | | ± 100 | nA |
| Zero Gate Voltage Drain Current | I_{DSS} | $V_{DS} = 20\text{ V}$, $V_{GS} = 0\text{ V}$ | | | 1 | μA |
| | | $V_{DS} = 20\text{ V}$, $V_{GS} = 0\text{ V}$, $T_J = 55\text{ }^\circ\text{C}$ | | | 10 | |
| On-State Drain Current ^a | $I_{D(on)}$ | $V_{DS} \geq 5\text{ V}$, $V_{GS} = 4.5\text{ V}$ | 5 | | | A |
| Drain-Source On-State Resistance ^a | $R_{DS(on)}$ | $V_{GS} = 4.5\text{ V}$, $I_D = 1.8\text{ A}$ | | 0.180 | 0.216 | Ω |
| | | $V_{GS} = 2.5\text{ V}$, $I_D = 1.6\text{ A}$ | | 0.223 | 0.268 | |
| | | $V_{GS} = 1.8\text{ V}$, $I_D = 0.3\text{ A}$ | | 0.300 | 0.375 | |
| Forward Transconductance ^a | g_{fs} | $V_{DS} = 10\text{ V}$, $I_D = 1.8\text{ A}$ | | 3 | | S |
| Dynamic^b | | | | | | |
| Input Capacitance | C_{iss} | $V_{DS} = 10\text{ V}$, $V_{GS} = 0\text{ V}$, $f = 1\text{ MHz}$ | | 95 | | pF |
| Output Capacitance | C_{oss} | | | 24 | | |
| Reverse Transfer Capacitance | C_{rss} | | | 11 | | |
| Total Gate Charge | Q_g | $V_{DS} = 10\text{ V}$, $V_{GS} = 8\text{ V}$, $I_D = 1.8\text{ A}$ | | 2.0 | 3.0 | nC |
| | | $V_{DS} = 10\text{ V}$, $V_{GS} = 4.5\text{ V}$, $I_D = 1.8\text{ A}$ | | 1.2 | 1.8 | |
| Q_{gs} | | | 0.3 | | | |
| Q_{gd} | | | 0.15 | | | |
| Gate Resistance | R_g | $f = 1\text{ MHz}$ | 0.5 | 2.5 | 5.0 | Ω |
| Turn-On Delay Time | $t_{d(on)}$ | $V_{DD} = 10\text{ V}$, $R_L = 7.1\text{ }\Omega$ $I_D \cong 1.4\text{ A}$, $V_{GEN} = 4.5\text{ V}$, $R_g = 1\text{ }\Omega$ | | 5 | 10 | ns |
| Rise Time | t_r | | | 10 | 20 | |
| Turn-Off Delay Time | $t_{d(off)}$ | | | 24 | 36 | |
| Fall Time | t_f | | | 8 | 16 | |
| Turn-On Delay Time | $t_{d(on)}$ | $V_{DD} = 10\text{ V}$, $R_L = 7.1\text{ }\Omega$ $I_D \cong 1.4\text{ A}$, $V_{GEN} = 8\text{ V}$, $R_g = 1\text{ }\Omega$ | | 2 | 4 | |
| Rise Time | t_r | | | 9 | 18 | |
| Turn-Off Delay Time | $t_{d(off)}$ | | | 8 | 16 | |
| Fall Time | t_f | | | 7 | 14 | |
| Drain-Source Body Diode Characteristics | | | | | | |
| Continuous Source-Drain Diode Current | I_S | $T_C = 25\text{ }^\circ\text{C}$ | | | 1.5 ^c | A |
| Pulse Diode Forward Current | I_{SM} | | | | 5 | |
| Body Diode Voltage | V_{SD} | $I_S = 1.4\text{ A}$, $V_{GS} = 0\text{ V}$ | | 0.7 | 1.2 | V |
| Body Diode Reverse Recovery Time | t_{rr} | $I_F = 1.4\text{ A}$, $di/dt = 100\text{ A}/\mu\text{s}$, $T_J = 25\text{ }^\circ\text{C}$ | | 9 | 18 | ns |
| Body Diode Reverse Recovery Charge | Q_{rr} | | | 3 | 6 | nC |
| Reverse Recovery Fall Time | t_a | | | 6 | | ns |
| Reverse Recovery Rise Time | t_b | | | 3 | | |

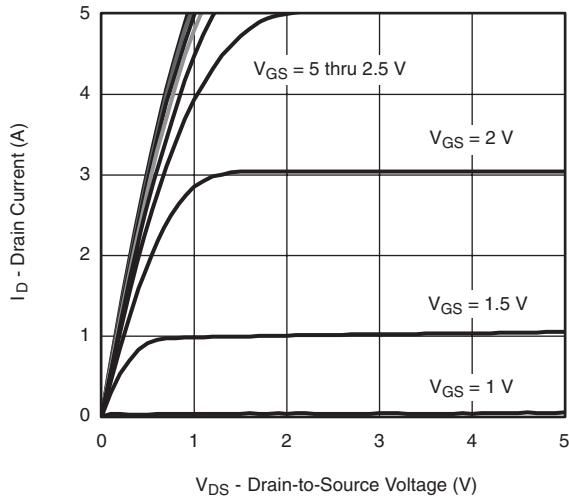
Notes:

- Pulse test; pulse width $\leq 300\text{ }\mu\text{s}$, duty cycle $\leq 2\%$.
- Guaranteed by design, not subject to production testing.
- Package limited.

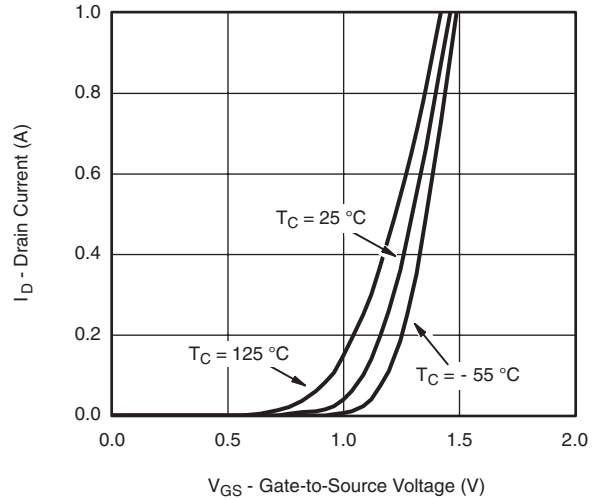
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



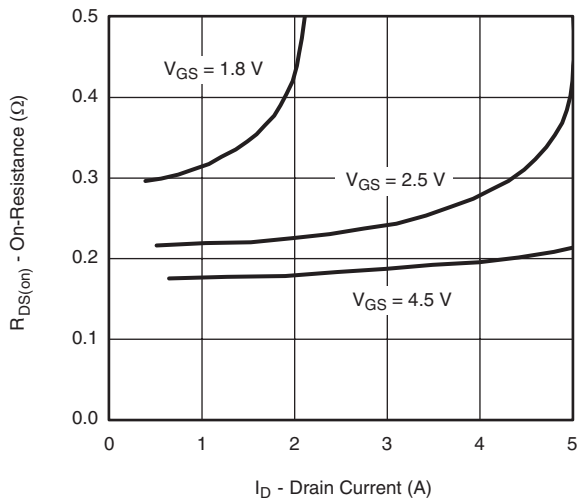
TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



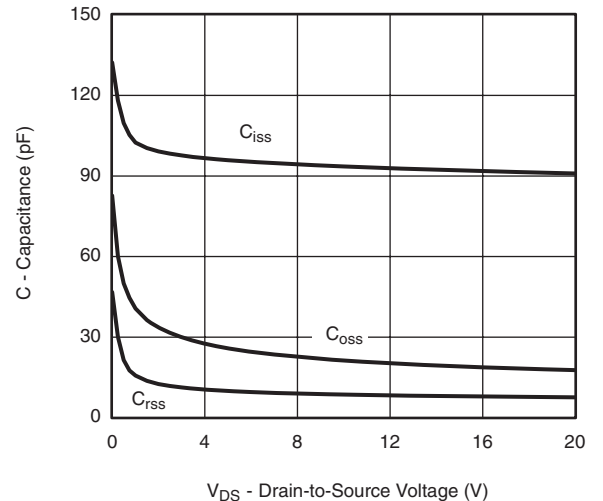
Output Characteristics



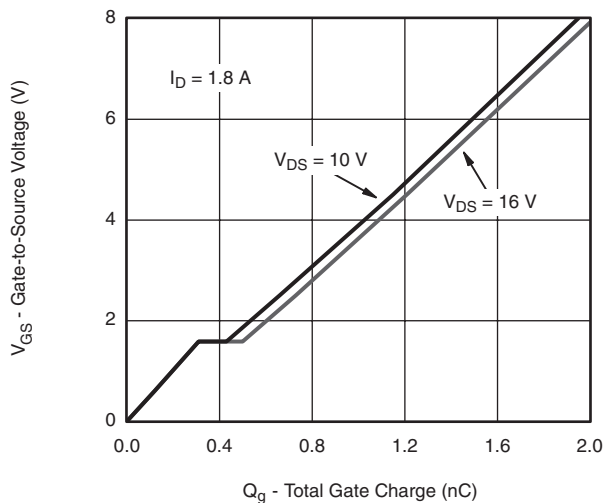
Transfer Characteristics



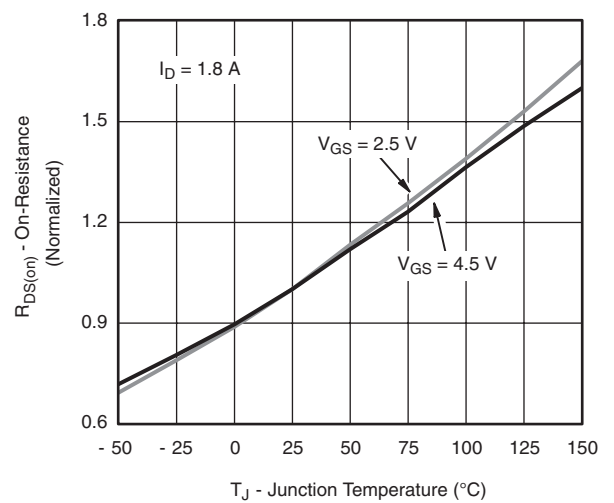
On-Resistance vs. Drain Current and Gate Voltage



Capacitance



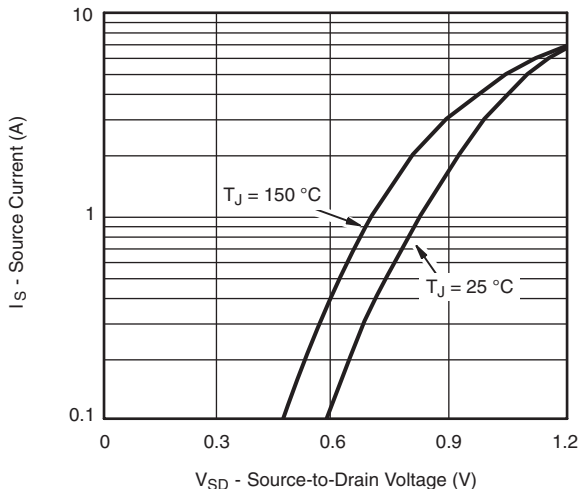
Gate Charge



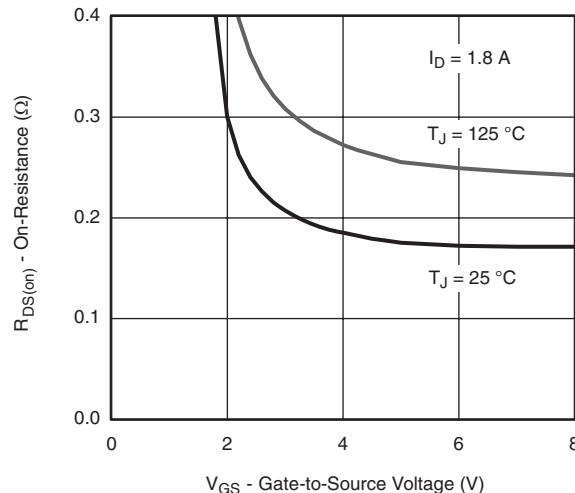
On-Resistance vs. Junction Temperature



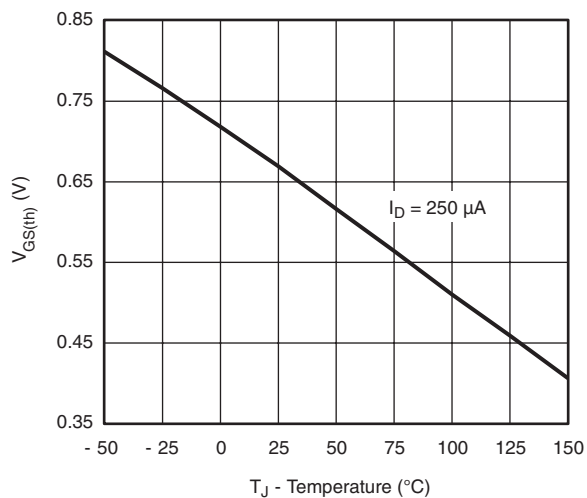
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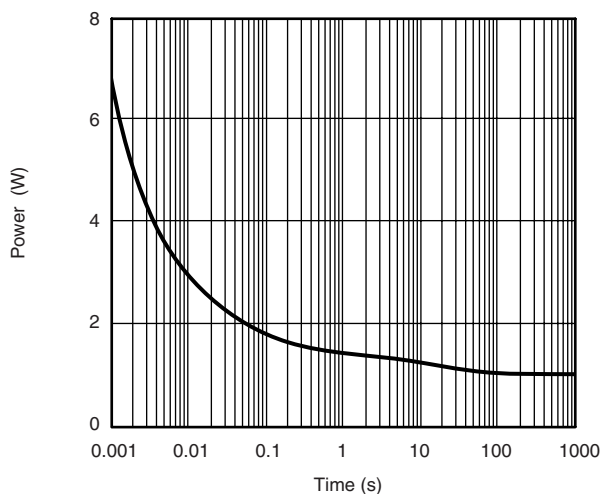
Source-Drain Diode Forward Voltage



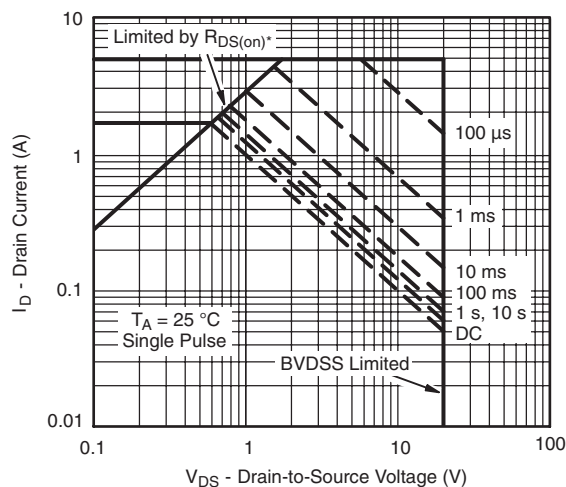
On-Resistance vs. Gate-to-Source Voltage



Threshold Voltage



Single Pulse Power, Junction-to-Ambient

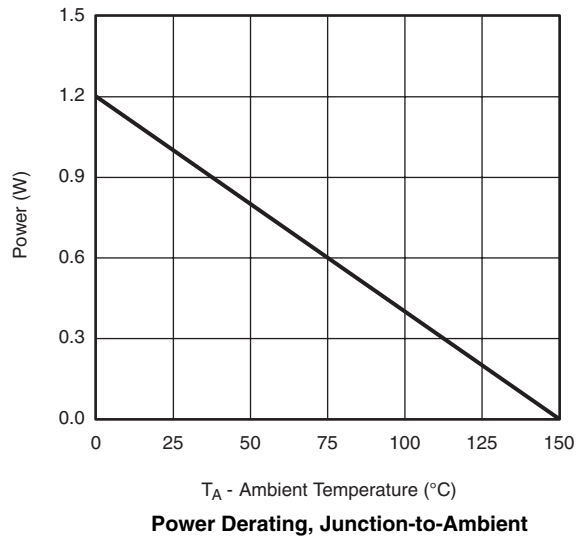
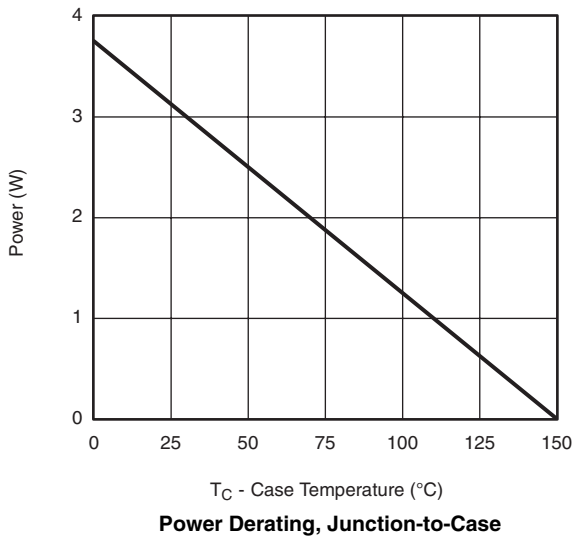
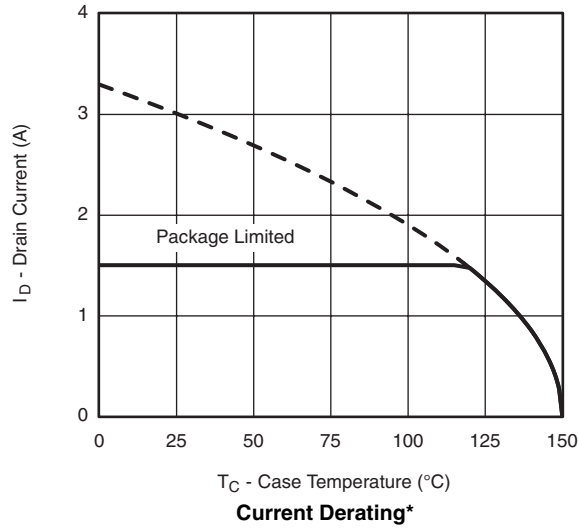


* $V_{GS} >$ minimum V_{GS} at which $R_{DS(on)}$ is specified

Safe Operating Area, Junction-to-Case



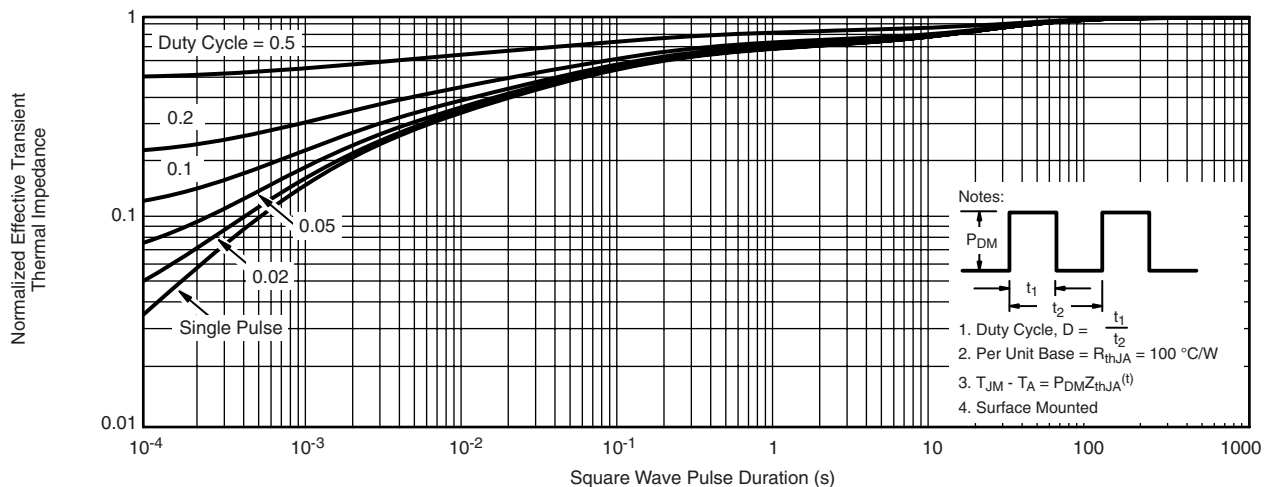
TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



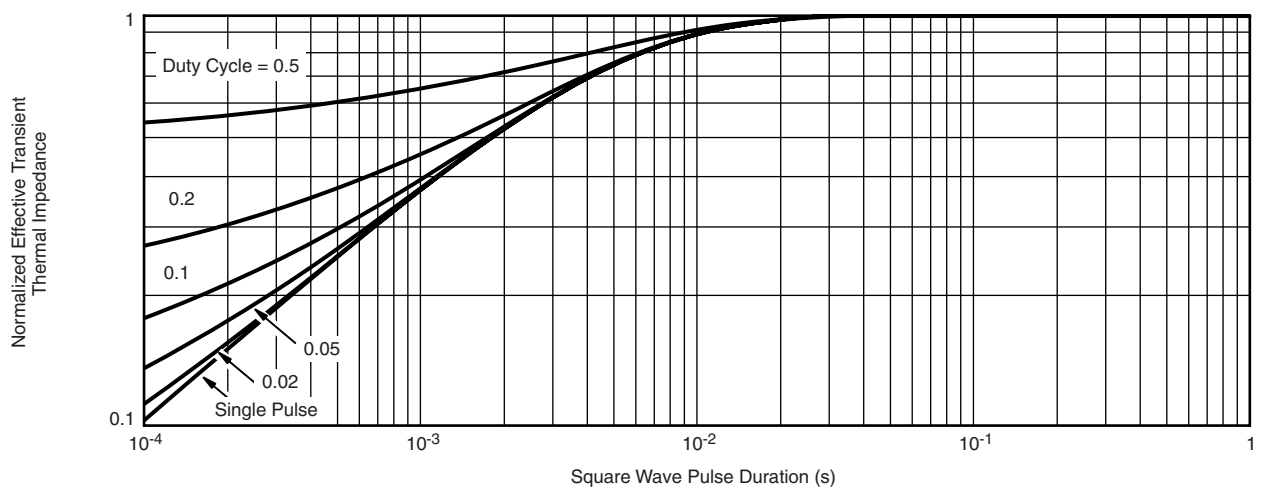
* The power dissipation P_D is based on $T_{J(max)} = 150$ °C, using junction-to-case thermal resistance, and is more useful in settling the upper dissipation limit for cases where additional heatsinking is used. It is used to determine the current rating, when this rating falls below the package limit.



TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



Normalized Thermal Transient Impedance, Junction-to-Ambient



Normalized Thermal Transient Impedance, Junction-to-Case

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PowerPAK® SC75-6L



BACKSIDE VIEW OF SINGLE

BACKSIDE VIEW OF DUAL

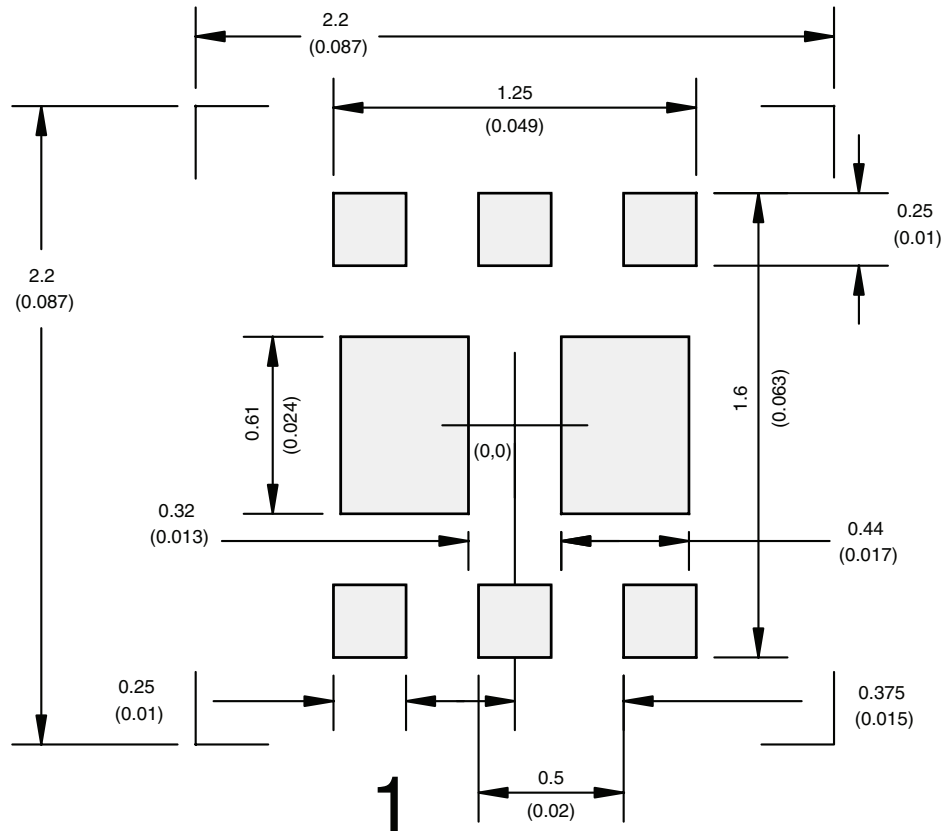


- Notes:
 1. All dimensions are in millimeters
 2. Package outline exclusive of mold flash and metal burr
 3. Package outline inclusive of plating

| DIM | SINGLE PAD | | | | | | DUAL PAD | | | | | |
|-----|-------------|------|------|-----------|-------|-------|-------------|------|------|-----------|-------|-------|
| | MILLIMETERS | | | INCHES | | | MILLIMETERS | | | INCHES | | |
| | Min | Nom | Max | Min | Nom | Max | Min | Nom | Max | Min | Nom | Max |
| A | 0.675 | 0.75 | 0.80 | 0.027 | 0.030 | 0.032 | 0.675 | 0.75 | 0.80 | 0.027 | 0.030 | 0.032 |
| A1 | 0 | - | 0.05 | 0 | - | 0.002 | 0 | - | 0.05 | 0 | - | 0.002 |
| b | 0.18 | 0.25 | 0.33 | 0.007 | 0.010 | 0.013 | 0.18 | 0.25 | 0.33 | 0.007 | 0.010 | 0.013 |
| C | 0.15 | 0.20 | 0.25 | 0.006 | 0.008 | 0.010 | 0.15 | 0.20 | 0.25 | 0.006 | 0.008 | 0.010 |
| D | 1.53 | 1.60 | 1.70 | 0.060 | 0.063 | 0.067 | 1.53 | 1.60 | 1.70 | 0.060 | 0.063 | 0.067 |
| D1 | 0.57 | 0.67 | 0.77 | 0.022 | 0.026 | 0.030 | 0.34 | 0.44 | 0.54 | 0.013 | 0.017 | 0.021 |
| D2 | 0.10 | 0.20 | 0.30 | 0.004 | 0.008 | 0.012 | | | | | | |
| E | 1.53 | 1.60 | 1.70 | 0.060 | 0.063 | 0.067 | 1.53 | 1.60 | 1.70 | 0.060 | 0.063 | 0.067 |
| E1 | 1.00 | 1.10 | 1.20 | 0.039 | 0.043 | 0.047 | 0.51 | 0.61 | 0.71 | 0.020 | 0.024 | 0.028 |
| E2 | 0.20 | 0.25 | 0.30 | 0.008 | 0.010 | 0.012 | | | | | | |
| E3 | 0.32 | 0.37 | 0.42 | 0.013 | 0.015 | 0.017 | | | | | | |
| e | 0.50 BSC | | | 0.020 BSC | | | 0.50 BSC | | | 0.020 BSC | | |
| K | 0.180 TYP | | | 0.007 TYP | | | 0.245 TYP | | | 0.010 TYP | | |
| K1 | 0.275 TYP | | | 0.011 TYP | | | 0.320 TYP | | | 0.013 TYP | | |
| K2 | 0.200 TYP | | | 0.008 TYP | | | 0.200 BSC | | | 0.008 TYP | | |
| K3 | 0.255 TYP | | | 0.010 TYP | | | | | | | | |
| K4 | 0.300 TYP | | | 0.012 TYP | | | | | | | | |
| L | 0.15 | 0.25 | 0.35 | 0.006 | 0.010 | 0.014 | 0.15 | 0.25 | 0.35 | 0.006 | 0.010 | 0.014 |
| T | | | | | | | 0.03 | 0.08 | 0.13 | 0.001 | 0.003 | 0.005 |

ECN: C-07431 – Rev. C, 06-Aug-07
 DWG: 5935

RECOMMENDED PAD LAYOUT FOR PowerPAK® SC75-6L Dual



Dimensions in mm/(Inches)

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